

SD1894

RF & MICROWAVE TRANSISTORS SATELLITE COMMUNICATIONS APPLICATIONS

- CLASS C
- ∎ 1.6 GHz
- COMMON BASE
- REFRACTORY/GOLD METALLIZATION
- EFFICIENCY = 50% MIN.
- P_{OUT} = 4.5 W MIN. WITH 10 dB GAIN



DESCRIPTION

The SD1894 is a common base silicon NPN bipolar device optimized for 1.6 GHz SATCOM applications.

The SD1894 offers superior gain and collector efficiency, making it an ideal choice for Class C power amplifiers used in portable as well as fixed SAT-COM terminals.



ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$)

Symbol	Parameter	Value	Unit	
Vсво	Collector-Base Voltage	45	V	
VCES	Collector-Emitter Voltage	45	V	
V _{EBO}	Emitter-Base Voltage	3.0	V	
Ι _C	Device Current	375	mA	
P _{DISS}	Power Dissipation	12.5	W	
TJ	Junction Temperature	+200	°C	
T _{STG}	Storage Temperature	- 65 to +150	C	

THERMAL DATA

R _{TH(j-c)} Junction-Ca	se Thermal Resistance	14.0	°C/W
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ELECTRICAL SPECIFICATIONS ($T_{case} = 25^{\circ}C$)

STATIC

Symbol	Toot Conditions	Value			Llm:4		
			Min.	Тур.	Max.	Onit	
ВУсво	$I_{C} = 1 \text{ mA}$	$I_E = 0 \text{ mA}$		45	—	_	V
BV _{CES}	$I_{C} = 1 \text{ mA}$	$V_{BE} = 0 V$		45	—	_	V
BV _{EBO}	$I_E = 1 \text{ mA}$	$I_{\rm C} = 0 \rm mA$		3.0	—		V
I _{СВО}	V _{CB} = 28 V	$I_E = 0 \text{ mA}$		—	—	.25	mA
h _{FE}	$V_{CE} = 5 V$	I _C = .2 A		15	_	150	_

DYNAMIC

Symbol	Test Conditions			Value			Unit
Symbol				Min.	Тур.	Max.	Onit
PIN	f = 1650 MHz	Vcc = 28 V	Pout = 4.5 W		.35	.45	W
ης	f = 1650 MHz	V _{CC} = 28 V	Pout = 4.5 W	50	55	_	%
PG	f = 1650 MHz	$V_{CC} = 28 V$	$P_{OUT} = 4.5 W$	10.0	11.1	_	dB
Load Mismatch	V _{CC} = 28 V	P _{OUT} = 4.5 W	VSWR = 20:1	No Degradation in Output Power			ו

INPUT POWER vs OUTPUT POWER





IMPEDANCE DATA



TEST CIRCUIT





SD1894

PACKAGE MECHANICAL DATA



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